HALOGEN FREE



Vishay General Semiconductor

Dual High-Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.51 \text{ V}$ at $I_F = 10 \text{ A}$



PRIMARY CHARACTERISTICS				
I _{F(AV)}	2 x 40 A			
V_{RRM}	170 V			
I _{FSM}	280 A			
V _F at I _F = 40 A	0.68 V			
T _J max.	175 °C			
Package	TO-3PW			
Diode variation	Dual common cathode			

FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses

• High efficiency operation

• Solder dip 275 °C max. 10 s, per JESD 22-B106

 Material categorization: For definitions of compliance please see www.vishav.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

MECHANICAL DATA

Case: TO-3PW

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and

commercial grade

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	V80170PW	UNIT	
Maximum repetitive peak reverse voltage		V _{RRM}	170	V	
Maximum average forward rectified current (fig. 1)	per device	I _{F(AV)}	80	^	
	per diode		40	А	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load		I _{FSM}	280	А	
Voltage rate of change (rated V _R)		dV/dt	10 000	V/µs	
Operating junction and storage temperature range		T _J , T _{STG}	-40 to +175	°C	



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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltage per diode	I _F = 10 A	T _A = 25 °C	V _F ⁽¹⁾	0.65	=	V	
	I _F = 20 A			0.74	-		
	I _F = 40 A			0.82	0.91		
	I _F = 10 A	T _A = 125 °C		0.51	-		
	I _F = 20 A			0.59	-		
	I _F = 40 A			0.68	0.76		
Reverse current per diode	V _R = 136 V	T _A = 25 °C	I _R ⁽²⁾	3.1	-	μA	
		T _A = 125 °C		3.8	-	mA	
	V _R = 170 V	T _A = 25 °C		-	600	μA	
		T _A = 125 °C		7.3	80	mA	

Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width \leq 20 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	V80170PW	UNIT	
Typical thermal resistance	per diode	$R_{ hetaJC}$	0.7	°C/W	
	per device		0.5	- C/VV	

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
TO-3PW	V80170PW-M3/4W	4.5	4W	30/tube	Tube	

RATINGS AND CHARACTERISTICS CURVES ($T_A = 25$ °C unless otherwise noted)

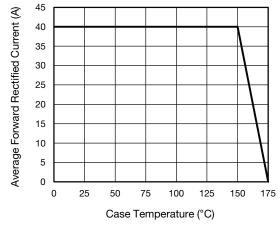


Fig. 1 - Maximum Forward Current Derating Curve

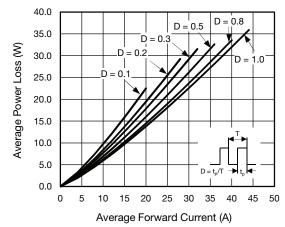


Fig. 2 - Forward Power Loss Characteristics Per Diode



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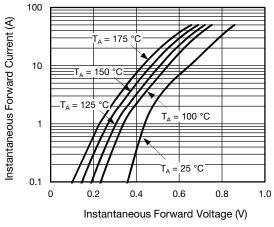


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

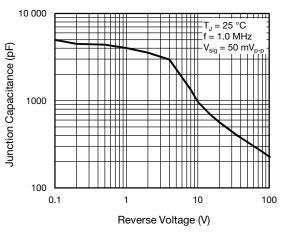


Fig. 5 - Typical Junction Capacitance Per Diode

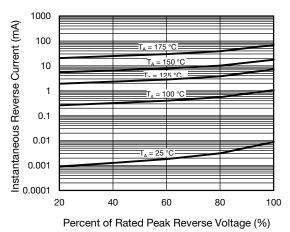


Fig. 4 - Typical Reverse Characteristics Per Diode

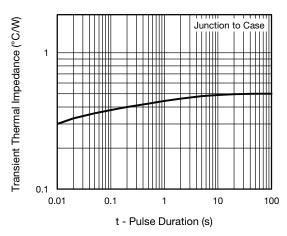
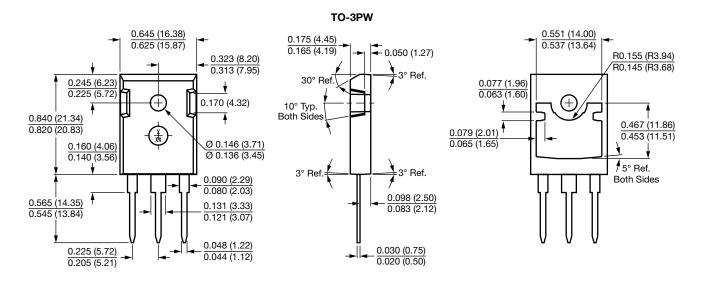


Fig. 6 - Typical Transient Thermal Impedance Per Device

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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Revision: 13-Jun-16 1 Document Number: 91000